

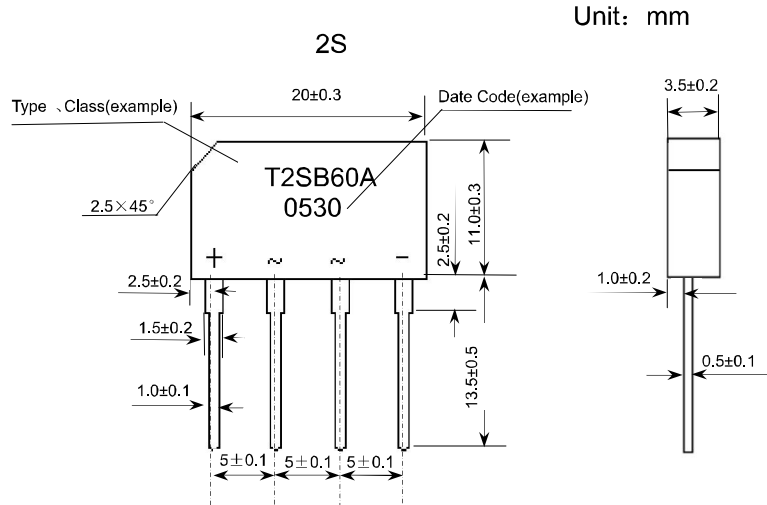
■ **Features**

- I_o 4.0A
- V_{RRM} 200V~800V
- Glass passivated chip
- High surge forward current capability
- Small size

■ **Applications**

- General purpose 1 phase Bridge rectifier applications

Outline Dimensions and Mark



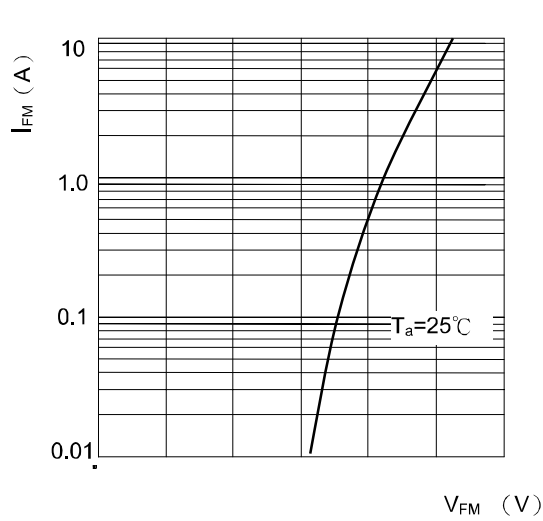
■ **Limiting Values (Absolute Maximum Rating)**

Item	Symbol	Unit	Conditions	T2SB20A	T2SB40A	T2SB60A	T2SB80A
Storage Temperature	T_{stg}	°C		-40 ~ +150			
Junction Temperature	T_j	°C		+150			
Repetitive Peak Reverse Voltage	V_{RRM}	V		200	400	600	800
Average Rectified Output Current	I_o	A	50Hz sine wave, R-load, $T_a=25$ °C	4.0			
Surge(Non-repetitive)Forward Current	I_{FSM}	A	50Hz sine wave, 1 cycle, $T_a=25$ °C	150			
Current Squared Time	I^2t	A ² s	1ms ≤ t < 8.3ms $T_j=25$ °C, Rating of per diode	93			

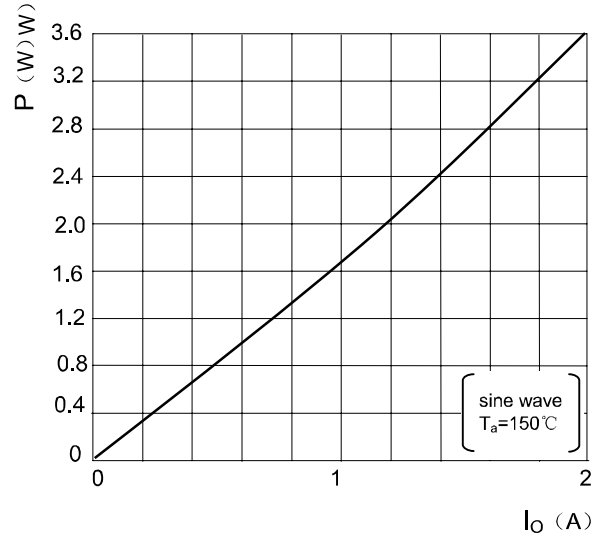
■ **Electrical Characteristics ($T_a=25$ °C Unless otherwise specified)**

Item	Symbol	Unit	Test Condition	Max
Peak Forward Voltage	V_{FM}	V	$I_{FM}=2A$, Pulse measurement, Rating of per diode	1.05
Peak Reverse Current	I_{RRM1}	μA	$V_{RM}=V_{RRM}$, Pulse measurement, Rating of per diode	5
Thermal Resistance	$R_{\theta J-A}$	°C/W	Between junction and ambient	47
	$R_{\theta J-L}$		Between junction and lead	10

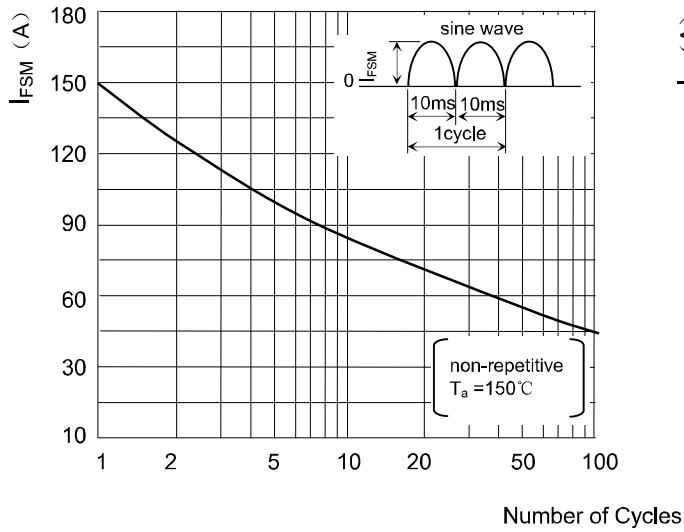
■ Characteristics(Typical)



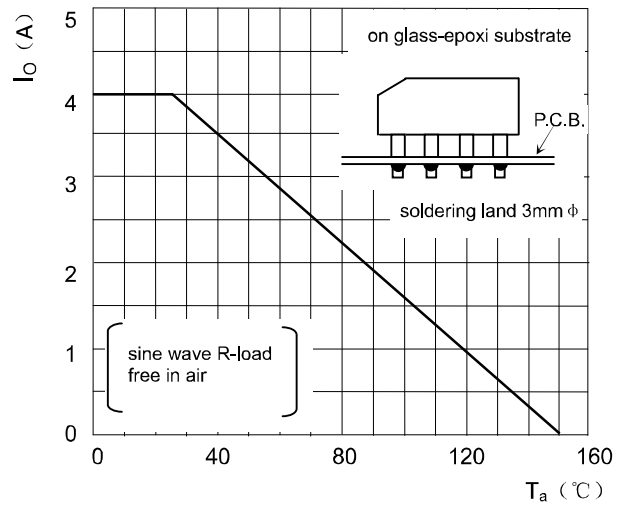
Forward Characteristics



P- I_o Curve



Surge Forward Current Capability



T_a - I_o Curve